

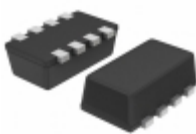



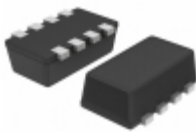
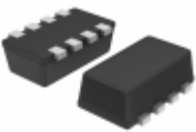
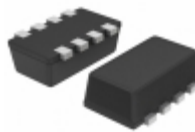

	<h2 style="color: red;">NTHD5904NT1G</h2>
	<p><b>Hersteller-Teilenummer:</b> NTHD5904NT1G</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 20V 2.5A CHIPFET</p> <p><b>Datenblätter:</b>  <a href="#">NTHD5904NT1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 30127 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NTHD5904NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 20V 2.5A CHIPFET
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	30127 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SMD, Flat Lead
Supplier Device-Gehäuse	ChipFET™
Verlustleistung (max)	640mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.5A (Ta)
Rds On (Max) @ Id, Vgs	65 mOhm @ 3.3A, 4.5V
VGS (th) (Max) @ Id	1.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	465pF @ 16V
Verpackung	Tape & Reel (TR)







NTHD5904NT1G ist neu im Original, Suche NTHD5904NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTHD5904NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTHD5904NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>NTHD5905T1</b> AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 3A CHIPFET</p>	 <p><b>NTHD5905T1G</b> ON NTHD5905T1G ON</p>	 <p><b>NTHD5904NT1</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 2.5A CHIPFET</p>	 <p><b>NTHD5903T1</b> ON NTHD5903T1 ON</p>
 <p><b>NTHD5904NT3</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 2.5A CHIPFET</p>	 <p><b>NTHD5904NT3G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 2.5A CHIPFET</p>	 <p><b>NTHD5904T1</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 20V 3.1A CHIPFET</p>	 <p><b>NTHD5904N</b> O NTHD5904N O</p>

### heiße Teile

Mehr

 NTHD3100CT1	 NTHD3101FT1	 NTHD3101FT1G	 NTHD3102CT1G	 NTHD310FT1G
 NTHD3133PFT1G	 NTHD4102PT1	 NTHD4102PT1G	 NTHD4401PT1G	 NTHD4401PT3G
 NTHD4502NT1	 NTHD4502NT1G	 NTHD4508NT1	 NTHD4508NT1G	 NTHD4N02FT1
 NTHD4N02FT1G	 NTHD4P02FT1	 NTHD4P02FT1-D	 NTHD4P02FT1G	 NTHD5902
 NTHD5902T1	 NTHD5903T1	 NTHD5903T1G	 NTHD5904N	 NTHD5904NT1
 NTHD5905T1	 NTHD5905T1G	 NTHS0402N02N1002HE	 NTHS0603N01N1003JE	 NTHS0603N02N6801
 NTHS0603N02N6801JE	 NTHS0805N01N5002JE	 NTHS1206N01N4702JE	 NTHS1206N02N1002JR	 NTHS1206N02N1002KR
 NTHS2101PT1	 NTHS2101PT1G	 NTHS4101PT1	 NTHS4101PT1G	 NTHS4111PT1
 NTHS4166NT1G	 NTHS4501NT1	 NTHS4501NT1G	 NTHS5404T1	 NTHS5404T1G
 NTHS5441T1	 NTHS5441T1G	 NTHS5443T1	 NTHS5443T1G	 NTHS5443T1H

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